

- Normal strain
- 2. Shear strain
- 3. Measurement of strain
- 4. Definition of normal and shear stress
- Method of sections
- 6. Hookes Law
- Axially loaded bars

# Strain and stress in one dimension

#### **EPFL**

### **Stiffness vs Strength**

Stiffness governs the amount a structure is deformed as a result of a load

Strength governs how much load a structure can hold without failing

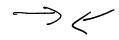
Strain: the deformation of a structure due to a load normalized to it's initial size and shape

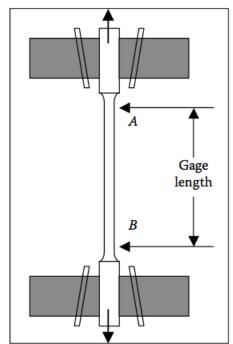
Gauge length: initial, undeformed length on the structure of interest

Tensile forces: Forces that tend to stretch or elongate the structure

Compressive forces: Forces that tend to compress or shorten the structure







$$L = 1.1 m$$

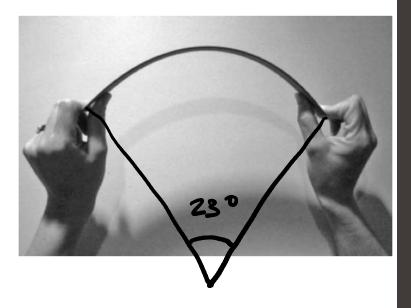
STRAIN 
$$E = \frac{\Delta L}{L_0} = \frac{L - L_0}{L_0}$$

# Definition of macroscopic strain

$$\varepsilon = \frac{L - L_0}{L_0} = \frac{\Delta L}{L_0}$$

 $\varepsilon > 0$  for tensile forces  $\varepsilon < 0$  for compressive forces





# **Example: Strain in a bent** ruler

A thin 12cm long ruler is deformed into a circular arc with radius 30cm. In the deformed state, the ruler makes an arc length encompassing 23degr. What is the strain in the ruler?

#### Assumptions:

ruler length: 12cm deformation into a circular arc r=30cm enclosed angle = 23 degree ruler is thin!

#### Asked:

find maximum normal strain in ruler

GOVERNING GQUATIONS ANSWER: L= ARCLENGIH = r. p = 30 cm · 23°. 2tt rud Given: Lo= 12 cm  $\phi$  = 23° = 12,04277... cm r = 30 cm E = 12.0 4277 - 12 ASKED: STRAIN IN BENTRACER: E ASSUMPTIONS: VULER MAKES CIRCULAR ARC.

Lo= 12 cm

**EPFL** 

**Definition of microscopic strain** 

u(x+dx)

M(x): THE DISTANCE THAT THE A PLANAR SECTION

HOS MOUGH IN THE

DIRECTION OF ECONSATION

DUE TO THE LOAD

WHAT IS  $\varepsilon$  OF SECTION dx:  $L_0 = dx$   $\begin{cases}
L_0 = dx \\
1^{ST} & \text{OK OSE:} \\
L = dx + u(x+dx) - u(x)
\end{cases}$ 

=) U(x+dx) = U(x) + U'(x) (x+dx -x) = U(x+dx) + U'(x) · dx

1 (=) u

2E) xtdx

ME-231B / STRIICTHBAL MECHANIC

## **Definition of microscopic strain**

$$\varepsilon = \frac{u(x) dx + dx - dx}{dx} = u'(x) = \frac{du}{dx}$$

LOCAL STRAIN IS THE FIRST DERIVATIVE OF THE

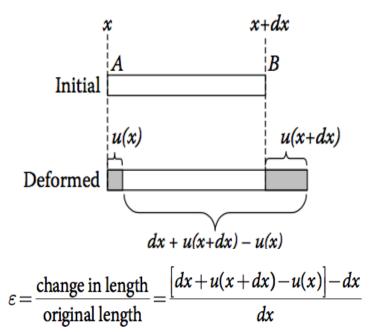
DISPLACEMENT?

U

DERIVATIVE OF THE



u(x):= the distance a planar section has moved in the direction of the elongation due to the load



Taylor series expansion of u(x+dx)

# **Definition of microscopic strain**

$$\varepsilon \cong \frac{[u(x) + u'(x)dx - u(x)]}{dx} = u'(x) = \frac{du}{dx}$$

#### **EPFL**

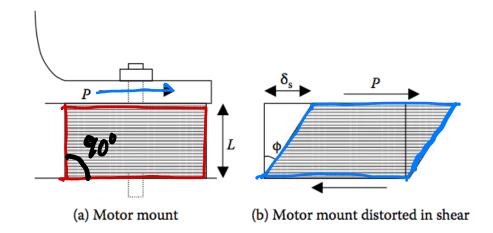
#### **Shear strain**

 Shear strain: angular distortion as a result of an applied load

#### definitions:

Engineering shear strain: the angular change (phi) in an initially right angle due to an applied force

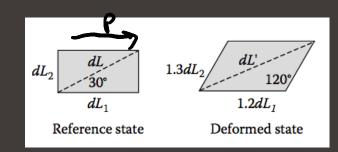
For small deformations we approximate phi by tan(phi)



$$\phi \cong \tan \phi = \frac{\delta_s}{L}$$
  $\phi < 1$ 

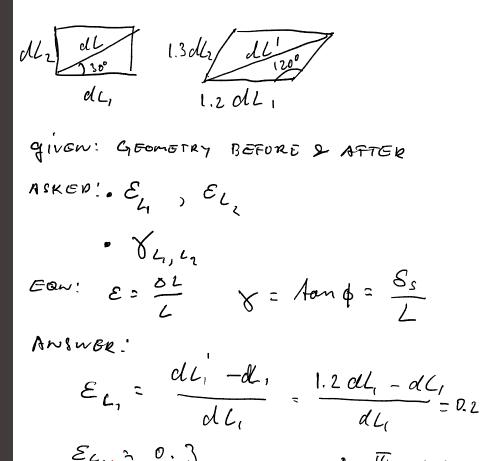


### **Example: Shear strain**



An infinitesimal rectangle at a point in a reference state of a material becomes a parallelogram shown in ta deformed state. Determine:

- a) The extensional strain in the dL direction
- B) The extensional strain in the dL<sub>2</sub> direction
- C) The shear strain coresponding to the dL₁ and dL₂ directions.



# $GF = rac{rac{\Delta R}{R}}{arepsilon} = rac{rac{\Delta R}{R}}{rac{\Delta L}{L_0}}$

# Measurement of strain: strain gauges

Strain gauges change their resistance as a function of strain

strain gauges can be made of different materials:

metal wire

metal thin film

semiconductors (especially doped silicon)

nanogranular materials

. . .

Gauge factor (GF): relative change in resistance due to strain

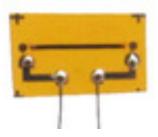


# **Different types of strain gauges**

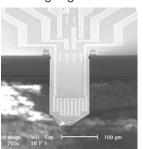
Foil strain gauge, GF=ca 2

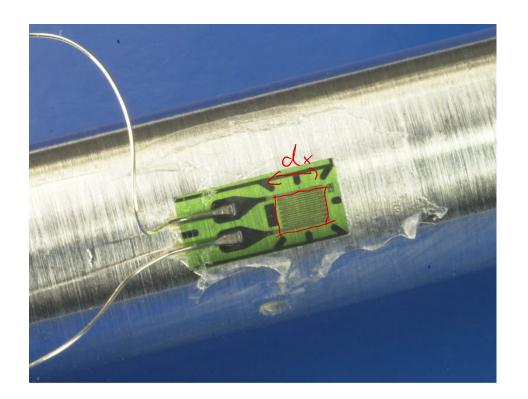


semiconductor strain gauge GF=ca 100

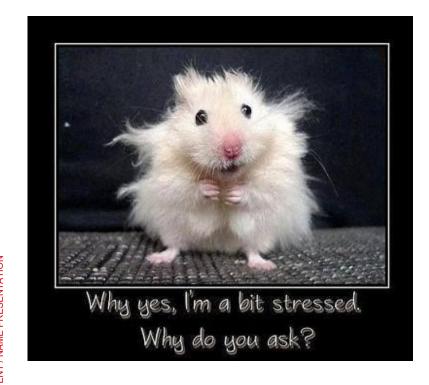


MEMS cantilever with embedded doped Si strain gauges GF=ca 30









## **Stress**

The internal response of structures to external loads

27 = Po-P, =0 (=> Po-P,

a o A SECOND ATOM.

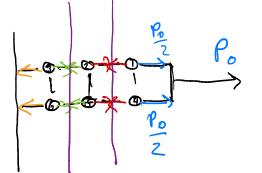
 $\frac{P_3}{P_2} = \frac{P_3}{P_2} + \frac{P_2}{P_3} = 0 \Rightarrow P_2 = P_3$ JEF = -P5 + Pn - P3 + P2 - P1 + P0 = 0

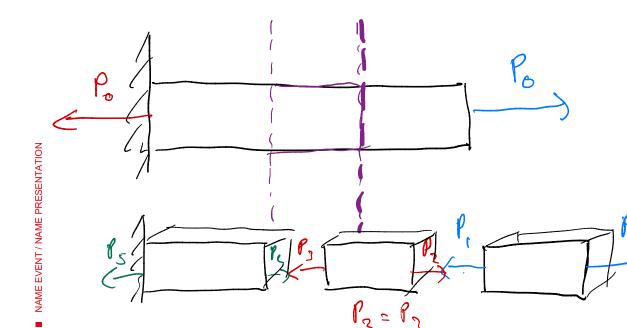
 $\left(P_{4}-P_{5}\right)+\left(P_{2}-P_{3}\right)+\left(P_{0}-P_{1}\right)=0$ 

IF WHOLE STRUCTURE IS IN EQUILIBRIUM

=) EACH ATOM BY ITSELF HAS TO BE IN EQUILIBRIUM

Speaker





$$P_{c} = P_{c}$$



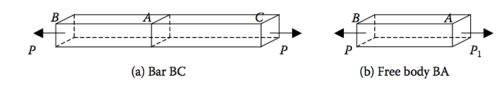
### **Stress = force per unit area**

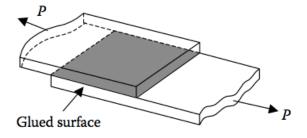
Normal stress at cross section A:

$$\sigma \equiv \frac{P}{A_1}$$



$$\tau \equiv \frac{P}{A_{\shortparallel}}$$



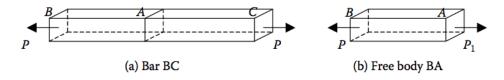


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#### **EPFL**

#### **Method of sections**

- Free body diagram (FBD): a schematic drawing with all the forces that act on the structure, including reaction forces through supports
- Method of sections:
  - perform a "virtual cut" through the body
  - each of the remaining pieces needs to be by itself in equilibrium. The internal forces that counter the external forces at that section are also present inside the whole body.

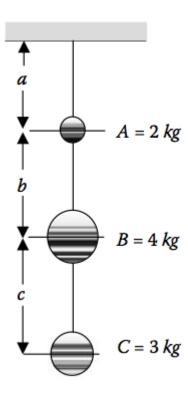


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#### **EPFL**

### **Example: Stress in wires**

- Three metal balls are suspended by three wires of equal length arranged in sequence as shown in the figure. The masses of the balls, starting at the top, are 2 kg, 4 kg, and 3 kg, respectively. In the same order, beginning at the top, the wires have diameters 2 mm, 1.5 mm, and 1 mm, respectively.
- (a) Determine the highest stressed wire, and
- (b) by changing the location of the balls, optimize the mass locations to achieve a system with minimum stresses.



Ø:2mm c) Vilm

GIVEN: \_ MASSES - dimbters

AIKED: STRESS IN WIRES ASSUMPTING. IGNORE MASS OF WIRES GOU. GON: O= P

- ORDER OF ARRANGEM ENT

 $O_{R} = \frac{9 \, \text{kg} \cdot \text{g}}{10 \, \text{kg}} = \frac{9 \cdot 9.8}{10 \, \text{c}} = 28.10$ 

ANSWER!

OB = 7.9 = 38,8 MPq

Oc = 37.4 Mla

Minimum STRESS

Example: TRUSSES A = 500 mm 21kN = Pg 21 kN 77F=0 I Fr = -Pg + Pcony quien: geometry. Losso: 20 k N =-Pg + 1/2 PcD = D · A = 500 mm Pan = 72. Pg ASKED: 0 = 1 & METHOD OF SECTION Gov. prive :

$$\sum_{x} F_{x} = -P_{ED} - P_{CD} \times = -P_{ED} - \frac{1}{2} \sqrt{2} \cdot P_{DC} = 0$$

$$-P_{ED} - \frac{1}{2}\sqrt{2}T_2P_q = 0$$

$$= P_{ED} = -P_q = -21bh$$

$$\sigma_{E0} = \frac{P_{E0}}{A} = -\frac{2 \cdot k_{0}}{500 \cdot 10 \, \text{m}^{2}} = -42 \, \text{M/a}$$

OLO => Compression 0 70 => TENSION

Speaker



